



FDPC4044

Common Drain N-Channel PowerTrench[®] MOSFET

30 V, 27 A, 4.3 mΩ

Features

- Max $r_{S1S2(on)}$ = 4.3 mΩ at $V_{GS} = 10\text{ V}$, $I_{S1S2} = 27\text{ A}$
- Max $r_{S1S2(on)}$ = 6.4 mΩ at $V_{GS} = 4.5\text{ V}$, $I_{S1S2} = 23\text{ A}$
- Package size/height: 3.3 x 3.3 x 0.8 mm
- Low inductance packaging shortens rise/fall times, resulting in lower switching losses
- MOSFET integration enables optimum layout for lower circuit inductance and reduced switch node ringing
- RoHS Compliant

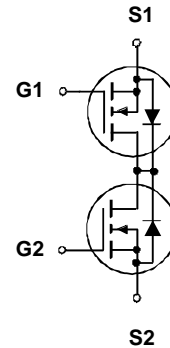
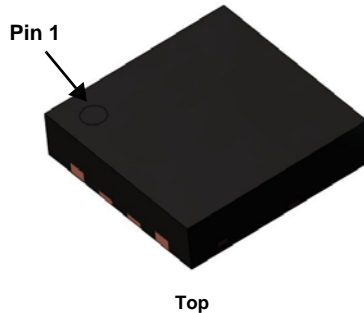
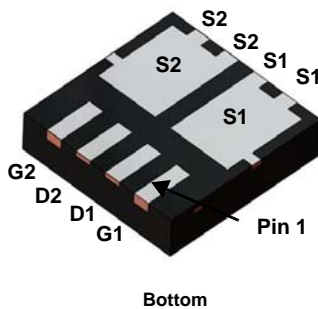


General Description

This device is designed specifically as a single package solution for Li-Ion battery pack protection circuit and other ultra-portable applications. It features two common drain N-channel MOSFETs, which enables bidirectional current flow. FDPC4044 combines Fairchild's advanced PowerTrench[®] process with state of the art packaging process to minimize the on-state resistance.

Applications

- Battery management
- Load switch
- Battery protection



Power Clip 33

MOSFET Maximum Ratings $T_A = 25\text{ °C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{S1S2}	Source1 to Source2 Voltage	30	V
V_{GS}	Gate to Source Voltage (Note 3)	±20	V
I_{S1S2}	Source1 to Source2 Current -Continuous $T_A = 25\text{ °C}$ (Note 1a)	27	A
	-Pulsed (Note 2)	120	
P_D	Power Dissipation $T_A = 25\text{ °C}$ (Note 1a)	2.7	W
	Power Dissipation $T_A = 25\text{ °C}$ (Note 1b)	1	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	47	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1b)	127	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
40CF	FDPC4044	Power Clip 33	13 "	12 mm	3000 units

Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

I_{S1S2}	Zero Gate Voltage Source1 to Source2 Current	$V_{S1S2} = 24\text{ V}, V_{GS} = 0\text{ V}$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = 20\text{ V}, V_{S1S2} = 0\text{ V}$			100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{S1S2}, I_{S1S2} = 250\text{ }\mu\text{A}$	1.2	1.5	3	V
$r_{S1S2(on)}$	Static Source1 to Source2 On Resistance	$V_{GS} = 10\text{ V}, I_{S1S2} = 27\text{ A}$		3.2	4.3	m Ω
		$V_{GS} = 4.5\text{ V}, I_{S1S2} = 23\text{ A}$		4.6	6.4	
		$V_{GS} = 10\text{ V}, I_{S1S2} = 27\text{ A}, T_J = 125\text{ }^\circ\text{C}$		4.5	7	
g_{FS}	Forward Transconductance	$V_{S1S2} = 10\text{ V}, I_{S1S2} = 27\text{ A}$		150		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{S1S2} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		2295	3215	pF
C_{oss}	Output Capacitance			627	880	pF
C_{riss}	Reverse Transfer Capacitance			66	95	pF

Switching Characteristics

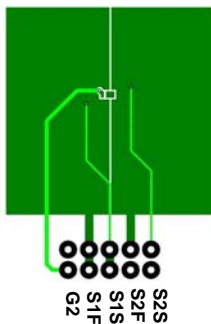
$t_{d(on)}$	Turn-On Delay Time	$V_{S1S2} = 15\text{ V}, I_{S1S2} = 27\text{ A}, V_{GS} = 10\text{ V}, R_{GEN} = 6\text{ }\Omega$		8.5	17	ns
t_r	Rise Time			4.8	10	ns
$t_{d(off)}$	Turn-Off Delay Time			32	52	ns
t_f	Fall Time			5.2	10	ns
Q_g	Total Gate Charge	$V_{S1S2} = 15\text{ V}, I_{S1S2} = 27\text{ A}, V_{G1S1} = 10\text{ V}, V_{G2S2} = 0\text{ V}$		35	49	nC
Q_{gs}	Gate to Source1 Gate Charge			5.7		nC
Q_{gd}	Gate to Source2 "Miller" Charge			4.7		nC

Source1 to Source2 Diode Characteristics

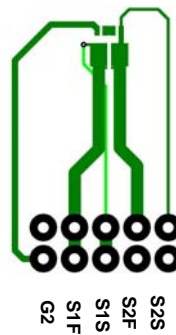
I_{fss}	Maximum Continuous Source1 to Source2 Diode Forward Current			1	A
V_{fss}	Source1 to Source2 Diode Forward Voltage	$V_{G1S1} = 0\text{ V}, V_{G2S2} = 4.5\text{ V}, I_{fss} = 27\text{ A}$ (Note 2)	0.8	1.2	V

Notes:

- $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 47 $^\circ\text{C/W}$ when mounted on a 1 in² pad of 2 oz copper.



b. 127 $^\circ\text{C/W}$ when mounted on a minimum pad of 2 oz copper.

- Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.

- As an N-ch device, the negative V_{gs} rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

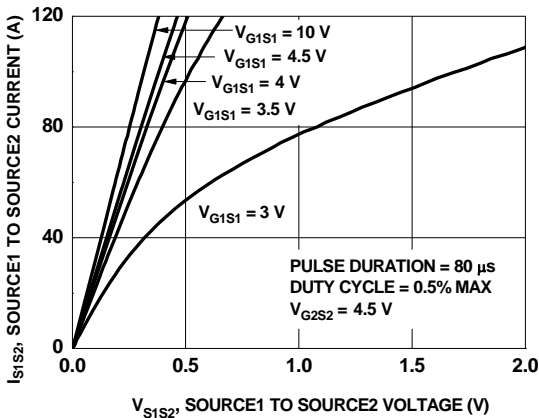


Figure 1. On-Region Characteristics

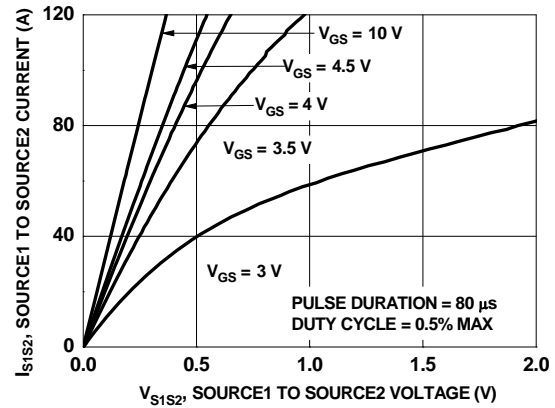


Figure 2. On-Region Characteristics

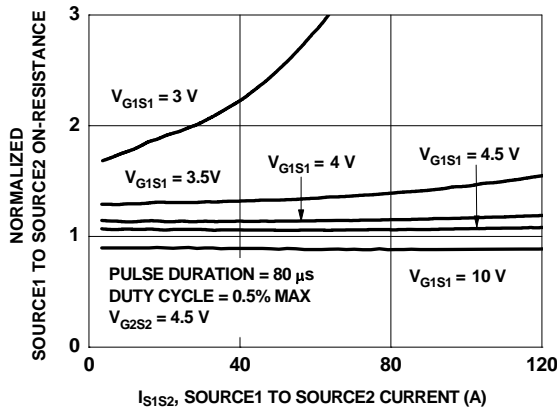


Figure 3. Normalized On-Resistance vs Source1 to Source2 Current and Gate Voltage

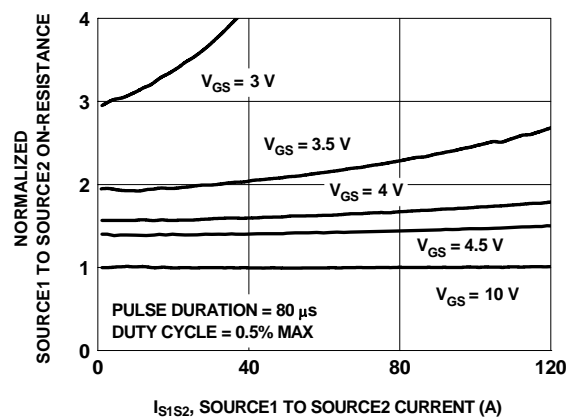


Figure 4. Normalized On-Resistance vs Source1 to Source2 Current and Gate Voltage

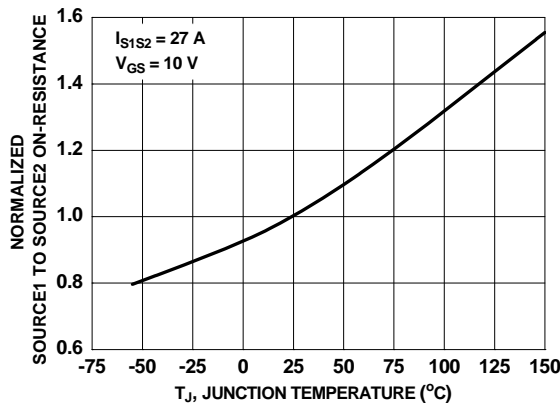


Figure 5. Normalized On-Resistance vs Junction Temperature

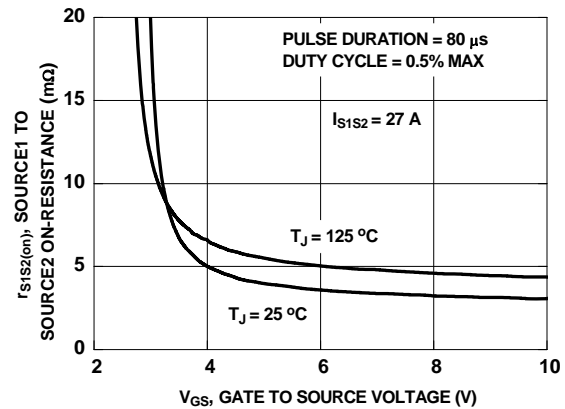


Figure 6. On-Resistance vs Gate to Source Voltage

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

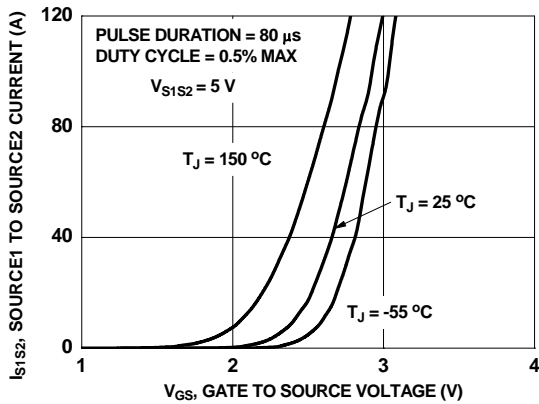


Figure 7. Transfer Characteristics

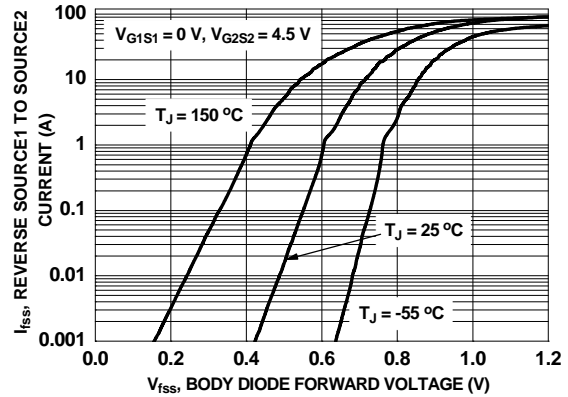


Figure 8. Source1 to Source2 Diode Forward Voltage vs Source Current

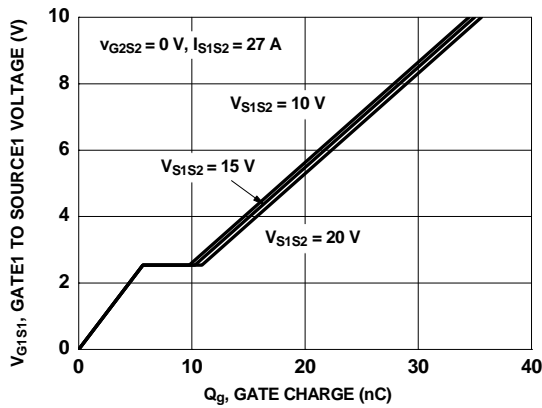


Figure 9. Gate Charge Characteristics

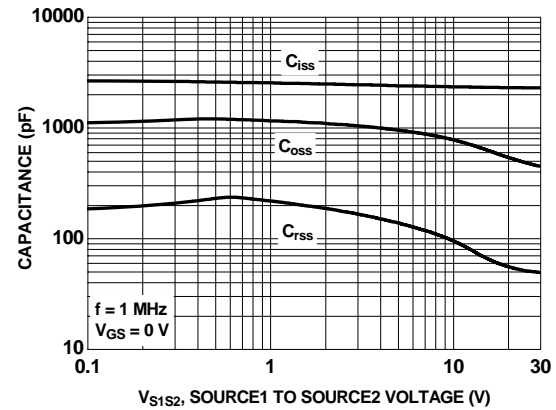


Figure 10. Capacitance vs Source1 to Source2 Voltage

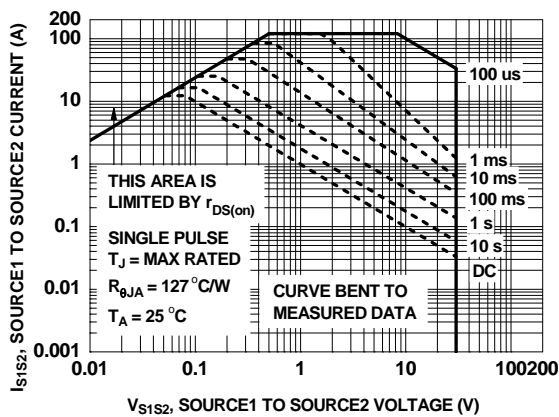


Figure 11. Forward Bias Safe Operating Area

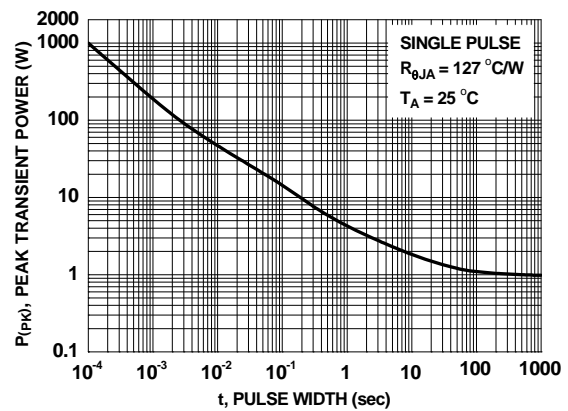


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

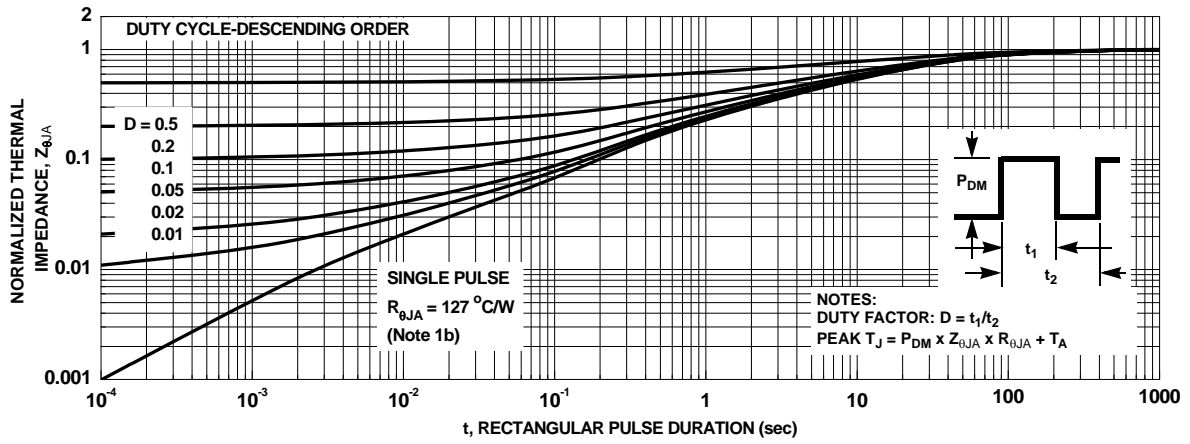
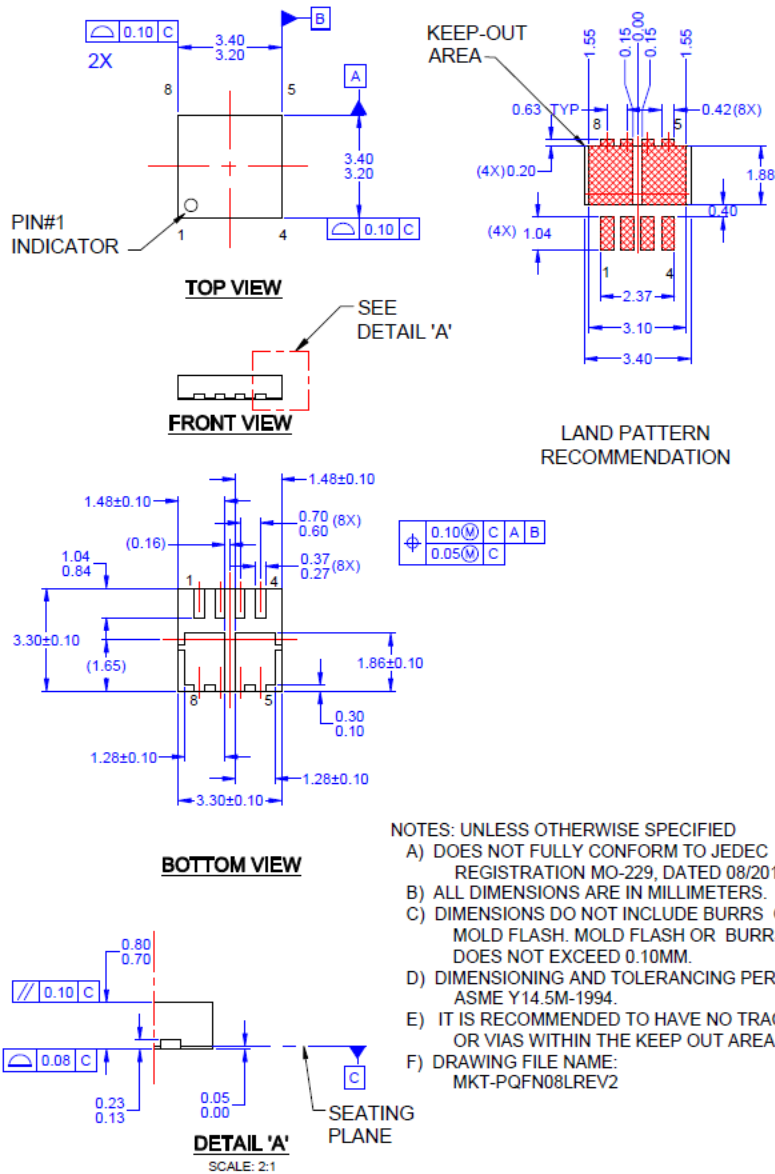


Figure 13. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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